



General Description

The IRFS4310ZTRLPBF use advanced SGT MOSFET technology

to provide low RDS(ON), low gate charge, fast switching

and excellent avalanche characteristics.

This device is specially designed to get better ruggedness

and suitable to use in



TO-263

General Features

$V_{DS} = 100V$ $I_D = 260A$

$R_{DS(ON)} < 2.8m\Omega$ @ $V_{GS}=10V$

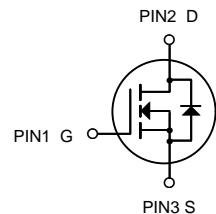
Applications

Consumer electronic power supply Motor control

N-Channel MOSFET

Synchronous-rectification Isolated DC

Synchronous-rectification applications



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
IRFS4310ZTRLPBF	TO-263	FS4310Z XXXX	800

Absolute Maximum Ratings at $T_j=25^\circ C$ unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	260	A
		163	
Pulsed Drain Current ¹	I_{DM}	1028	A
Single Pulse Avalanche Energy ²	E_{AS}	583	mJ
Total Power Dissipation	P_D	379	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C
Thermal Resistance from Junction-to-Ambient ³	$R_{\theta JA}$	59	°C/W
Thermal Resistance from Junction-to-Case	$R_{\theta JC}$	0.33	°C/W



Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	100	-	-	V
Gate-body Leakage current	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	± 100	nA
Zero Gate Voltage Drain Current	$T_J=25^\circ\text{C}$	$I_{BS}\text{ss}$	$V_{DS}=100V, V_{GS}=0V$	-	-	1
	$T_J=100^\circ\text{C}$			-	-	100
Gate-Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	2	3	4	V
Drain-Source on-Resistance ⁴	$R_{DS(\text{on})}$	$V_{GS} = 10V, I_D = 20A$	-	2.4	2.8	$\text{m}\Omega$
Forward Transconductance ⁴	g_{fs}	$V_{DS}=10V, I_D=20A$	-	76	-	S
Dynamic Characteristics⁵						
Input Capacitance	C_{iss}	$V_{DS} = 50V, V_{GS} = 0V, f = 1\text{MHz}$	-	9030	-	pF
Output Capacitance	C_{oss}		-	1505	-	
Reverse Transfer Capacitance	C_{rss}		-	40	-	
Gate Resistance	R_g	$f = 1\text{MHz}$	-	2.3	-	Ω
Switching Characteristics⁵						
Total Gate Charge	Q_g	$V_{GS} = 10V, V_{DS} = 50V, I_D = 20A$	-	150	-	nC
Gate-Source Charge	Q_{gs}		-	32.5	-	
Gate-Drain Charge	Q_{gd}		-	49	-	
Turn-on Delay Time	$t_{d(on)}$	$V_{GS} = 10V, V_{DD} = 50V, R_G = 3\Omega, I_D = 20A$	-	27	-	ns
Rise Time	t_r		-	78.5	-	
Turn-off Delay Time	$t_{d(off)}$		-	110	-	
Fall Time	t_f		-	86	-	
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 20A, dI/dt = 100A/\mu\text{s}$	-	88	-	ns
Body Diode Reverse Recovery Charge	Q_{rr}		-	220	-	nC
Drain-Source Body Diode Characteristics						
Diode Forward Voltage ⁴	V_{SD}	$I_D = 20A, V_{GS} = 0V$	-	-	1.2	V
Continuous Source Current	$T_C = 25^\circ\text{C}$	I_s	-	-	260	A

Notes:

1. Repetitive rating, pulse width limited by junction temperature $T_{J(\text{MAX})} = 150^\circ\text{C}$.
2. The EAS data shows Max. rating . The test condition is $V_{DD}=50V, V_{GS}=10V, L=0.4\text{mH}, I_{AS}=54A$.
3. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
4. The data tested by pulsed , pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
5. This value is guaranteed by design hence it is not included in the production test.



Typical Characteristics

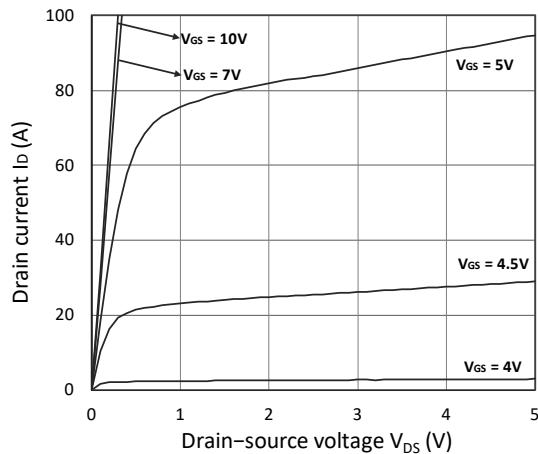


Figure 1. Output Characteristics

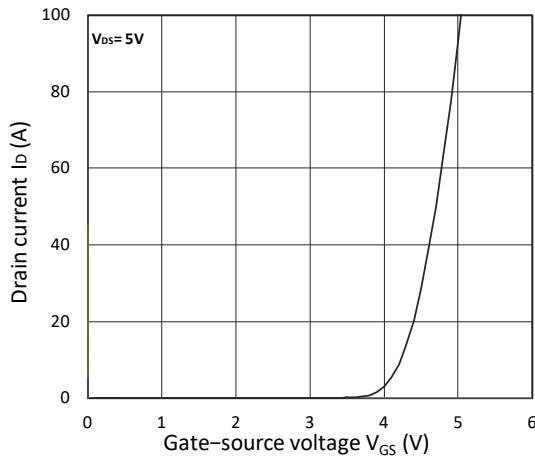


Figure 2. Transfer Characteristics

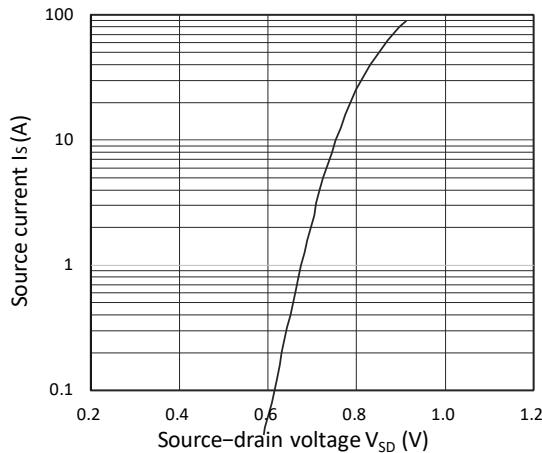


Figure 3. Forward Characteristics of Reverse

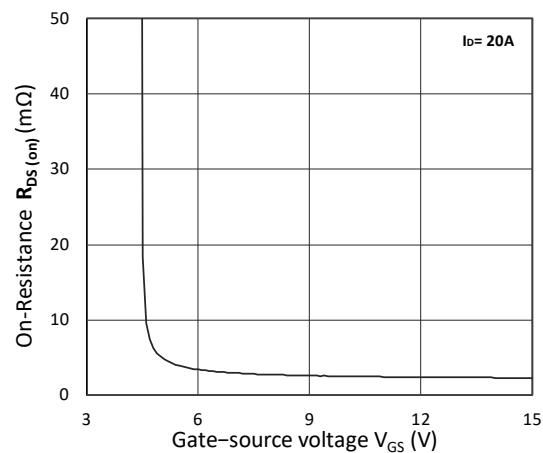


Figure 4. $R_{DS(ON)}$ vs. V_{GS}

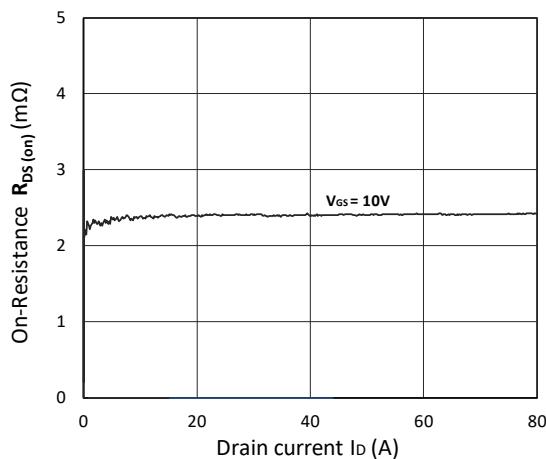


Figure 5. $R_{DS(ON)}$ vs. I_D

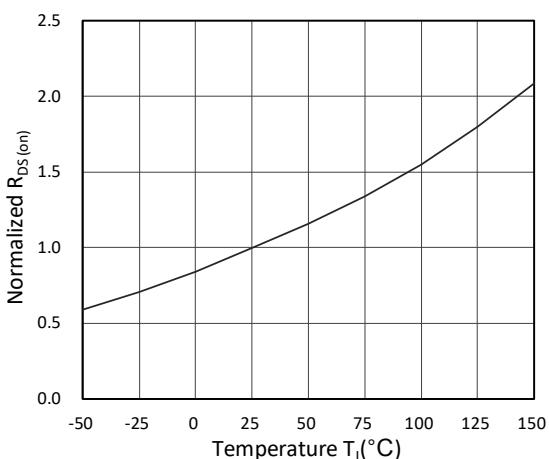


Figure 6. Normalized $R_{DS(ON)}$ vs. Temperature

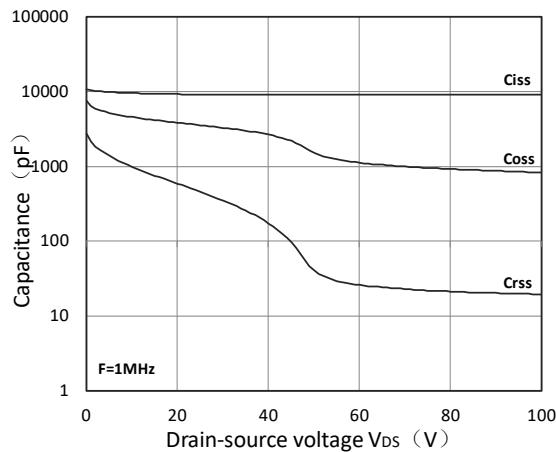


Figure 7. Capacitance Characteristics

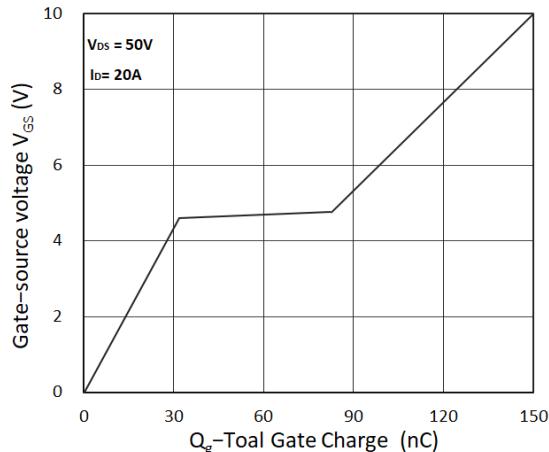


Figure 8. Gate Charge Characteristics

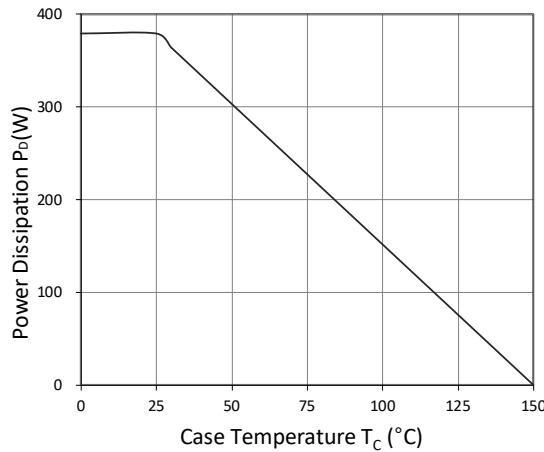


Figure 9. Power Dissipation

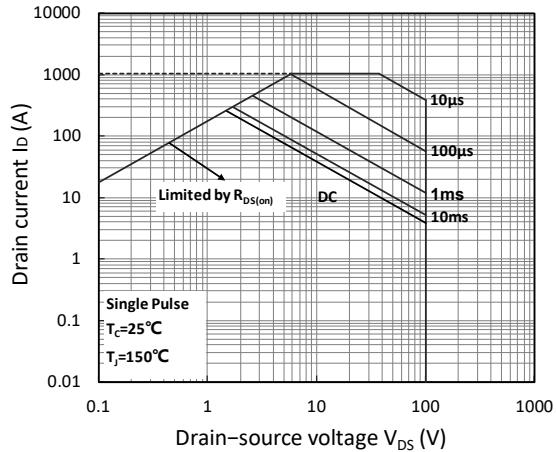


Figure 10. Safe Operating Area

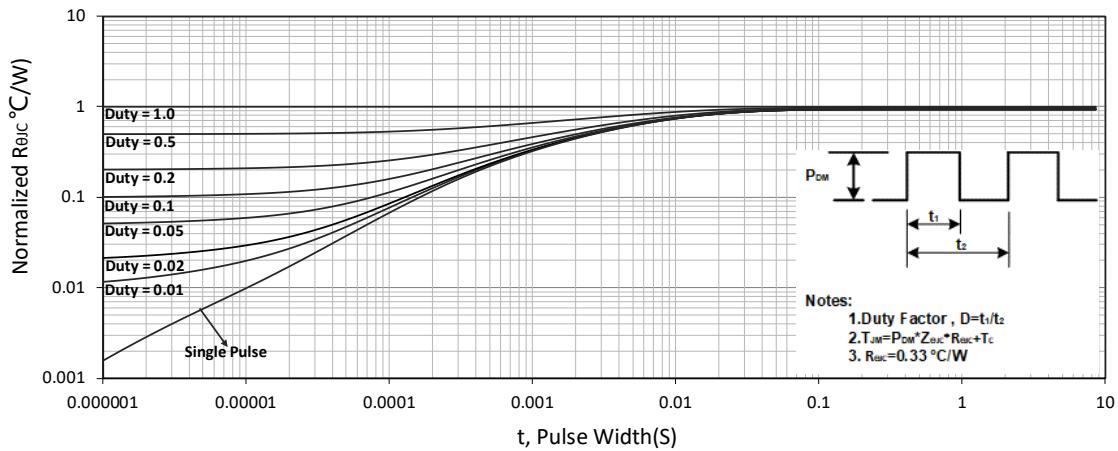


Figure 11. Normalized Maximum Transient Thermal Impedance



Test Circuit

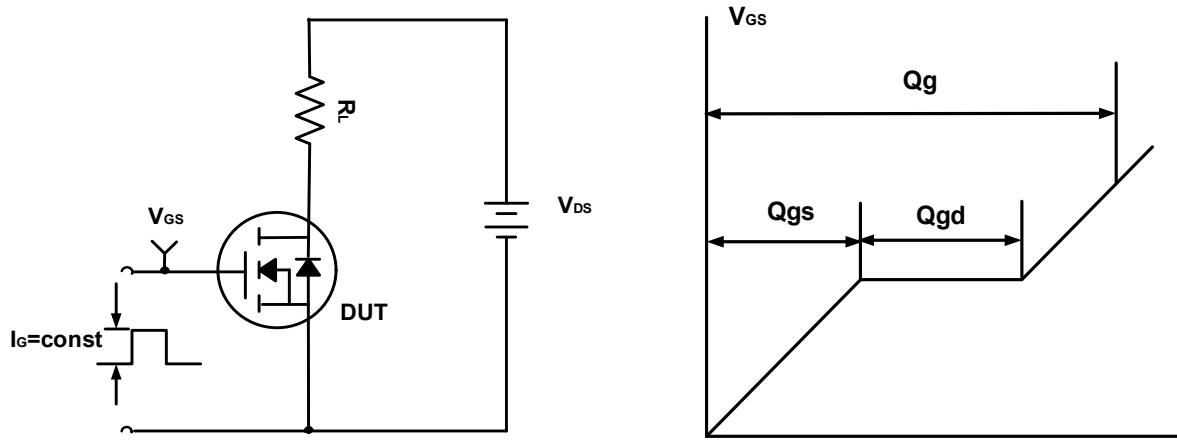


Figure A. Gate Charge Test Circuit & Waveforms

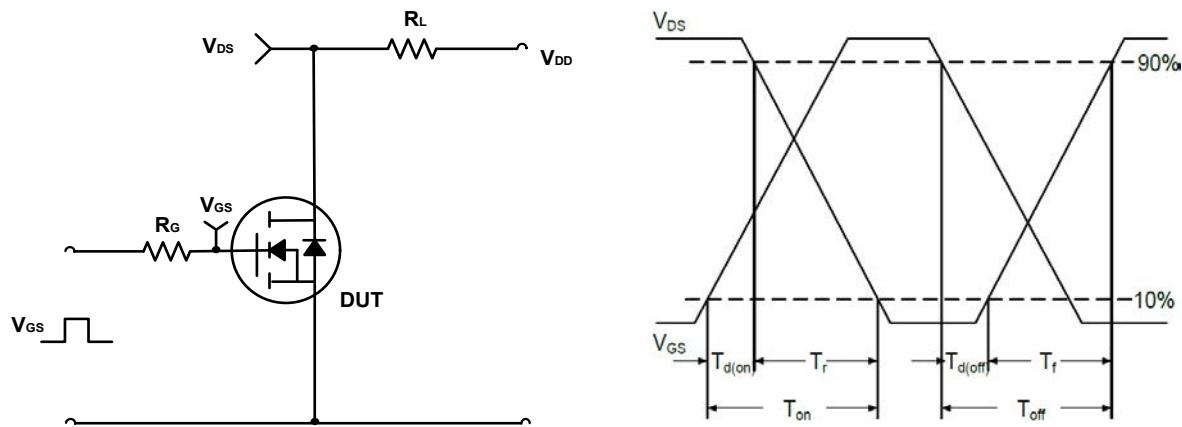


Figure B. Switching Test Circuit & Waveforms

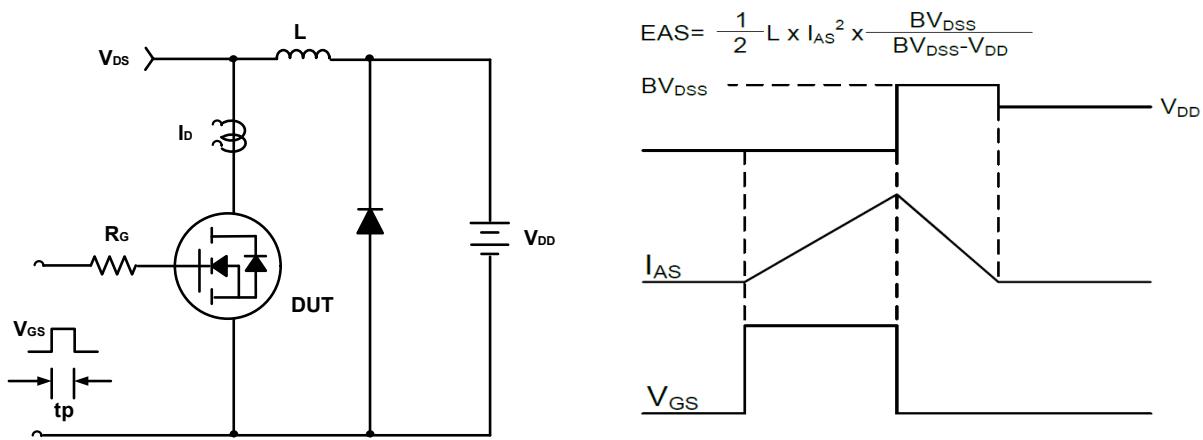
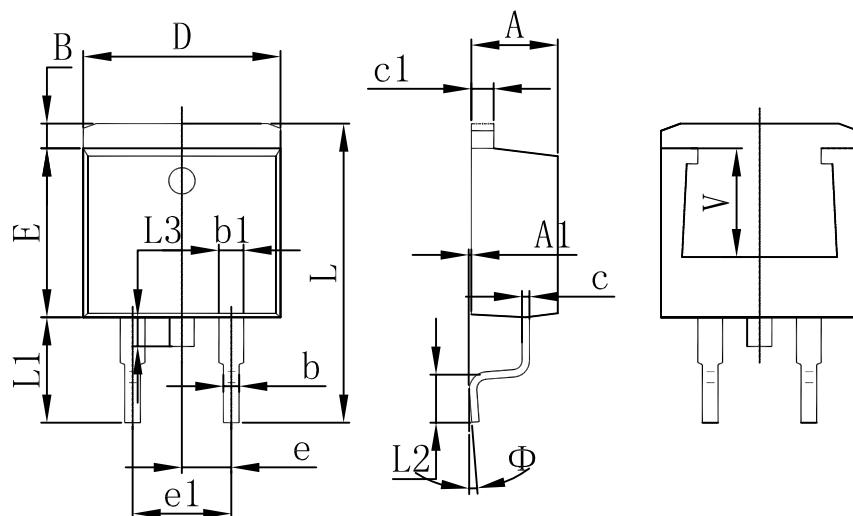


Figure C. Unclamped Inductive Switching Circuit & Waveforms



TO-263 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
B	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0°	8°	0°	8°
V	5.600 REF.		0.220REF.	



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